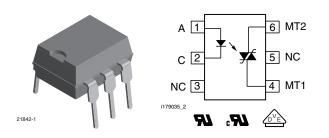
Optocoupler, Phototriac Output, High dV/dt, Low Input Current



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DESCRIPTION

The VO4257 and VO4258 phototriac consists of a GaAs IRLED optically coupled to a photosensitive non-zero crossing TRIAC packaged in a DIP-6 package.

High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver resulting in an LED trigger current of 1.6 mA for bin D, 2 mA for bin H, and 3 mA for bin M.

The new non zero phototriac family use a proprietary dV/dt clamp resulting in a static dV/dt of greater than 5 kV/ μ s.

The VO4257, VO4258 phototriac isolates low-voltage logic from 120 VAC, 240 VAC, and 380 VAC lines to control resistive, inductive, or capacitive loads including motors, solenoids, high current thyristors or TRIAC and relays.

FEATURES

- High static dV/dt 5 kV/µs
- High input sensitivity I_{FT} = 1.6 mA, 2 mA, and 3 mA
- 700 and 800 V blocking voltage
- 300 mA on-state current
- Isolation test voltage 5300 V_{RMS}
- Compliant to RoHS Directive 2011/65/EU

APPLICATIONS

- Solid-state relays
- Industrial controls
- Office equipment
- Consumer appliances

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) available with option 1

ORDERING INFORMATION								
V 0 4 2 5 # X - X 0 0 # T DP-6 Option 6 PART NUMBER PACKAGE OPTION TAPE AND REEL Option 7 0								
AGENCY	AGENCY V _{DRM} 700 V _{DRM} 800							
CERTIFIED/PACKAGE	TRIGGER CURRENT, I _{FT} (mA)							
UL, cUL, BSI, FIMKO	1.6	2	3	1.6	2	3		
DIP-6	VO4257D	VO4257H	V4257M	VO4258D	VO4258H	VO4258M		
DIP-6, 400 mil, option 6	VO4257D-X006	VO4257H-X006	VO4257M-X006	VO4258D-X006	VO4258H-X006	VO4258M-X006		
SMD-6, option 7	VO4257D-X007T	VO4257H-X007T	VO4257M-X007T	VO4258D-X007T	VO4258H-X007T	VO4258M-X007T		
VDE, UL, cUL, BSI, FIMKO	1.6	2	3	1.6	2	3		
SMD-6, option 7	-	-	-	-	VO4258H-X017T	-		

RoHS

COMPLIANT



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT		
INPUT							
Reverse voltage			V _R	6	V		
Forward current			١ _F	60	mA		
Derate from 25 °C				1.33	mW/°C		
OUTPUT							
Dools off state voltage		VO4257D/H/M	V _{DRM}	700	V		
Peak off-state voltage		VO4258D/H/M	V _{DRM}	800	V		
RMS on-state current			I _{TM}	300	mA		
Derate from 25 °C				6.6	mW/°C		
COUPLER							
Isolation test voltage (between emitter and detector, climate per DIN 500414, part 2, Nov. 74)	t = 1 s		V _{ISO}	5300	V _{RMS}		
Storage temperature range			T _{stg}	- 55 to + 150	°C		
Ambient temperature range			T _{amb}	- 55 to + 100	°C		
Soldering temperature	$\begin{array}{l} max. \leq 10 \text{ s dip soldering} \\ \geq 0.5 \text{ mm from case bottom} \end{array}$		T _{sld}	260	°C		

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

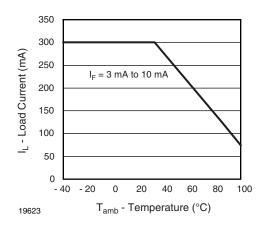


Fig. 1 - Recommended Operating Condition



THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P _{diss}	100	mW
Output power dissipation	P _{diss}	500	mW
Total power dissipation	P _{tot}	600	mW
Maximum LED junction temperature	T _{jmax.}	125	°C
Maximum output die junction temperature	T _{jmax.}	125	°C
Thermal resistance, junction emitter to board	θ_{JEB}	150	°C/W
Thermal resistance, junction emitter to case	θ_{JEC}	139	°C/W
Thermal resistance, junction detector to board	θ_{JDB}	78	°C/W
Thermal resistance, junction detector to case	θ_{JDC}	103	°C/W
Thermal resistance, junction emitter to junction detector	θ_{JED}	496	°C/W
Thermal resistance, case to ambient	θ_{CA}	3563	°C/W

Note

The thermal characteristics table above were measured at 25 °C and the thermal model is represented in the thermal network below. Each
resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal
resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation
of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note.

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT		1					•••••
Forward voltage	I _F = 10 mA		V _F		1.2	1.4	V
Reverse current	V _R = 6 V		I _R		0.1	10	μA
Input capacitance	$V_{F} = 0 V, f = 1 MHz$		CI		40		pF
OUTPUT					•	•	
Repetitive peak off-state voltage	100.4	VO4257D/H/M	V _{DRM}	700			V
	I _{DRM} = 100 μΑ	VO4258D/H/M	V _{DRM}	800			V
Off-state current	$V_D = V_{DRM}$		I _{DRM}			100	μA
On-state voltage	I _T = 300 mA		V _{TM}			3	V
On-current	PF = 1, V _{T(RMS)} = 1.7 V		I _{TM}			300	mA
Critical state of rise of off-state voltage	$V_D = 0.67 \ V_{DRM}, \ T_J = 25 \ ^\circ C$		dV/dt _{cr}	5000			V/µs
COUPLER					•	•	•
LED trigger current, current required to latch output	V _D = 3 V	VO4257D	I _{FT}			1.6	mA
		VO4257H	I _{FT}			2	mA
		VO4257M	I _{FT}			3	mA
		VO4258D	I _{FT}			1.6	mA
		VO4258H	I _{FT}			2	mA
		VO4258M	I _{FT}			3	mA
Capacitance (input to output)	f = 1 MHz, V _{IO} = 0 V		C _{IO}		0.8	1	pF

Note

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC68 part 1)				55/100/2 1			
Pollution degree (DIN VDE 0109)				2			
Comparative tracking index per DIN IEC112/ VDE 0303 part 1, group Illa per DIN VDE 6110 175 399			175		399		
V _{IOTM}		VIOTM	8000			V	
V _{IORM}		VIORM	890			V	
P _{SO}		P _{SO}			500	mW	
I _{SI}		I _{SI}			250	mA	
T _{SI}		T _{SI}			175	°C	
Creepage distance			7			mm	
Clearance distance			7			mm	

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

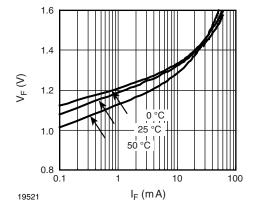


Fig. 2 - Diode Forward Voltage vs. Forward Current

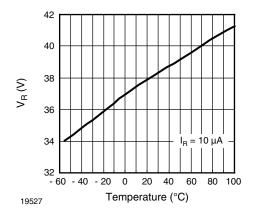


Fig. 3 - Diode Reverse Voltage vs. Temperature

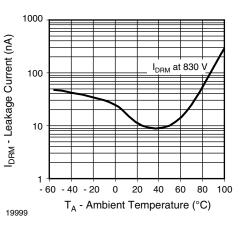


Fig. 4 - Leakage Current vs. Ambient Temperature

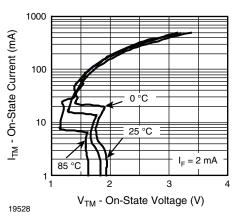
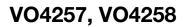


Fig. 5 - Output On Current (I_{TM}) vs. Voltage

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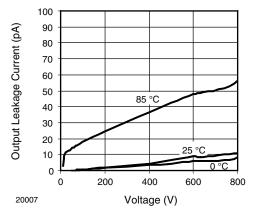


Fig. 6 - Output Off Current (Leakage) vs. Voltage

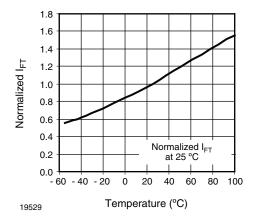


Fig. 7 - Normalized Trigger Input Current vs. Temperature

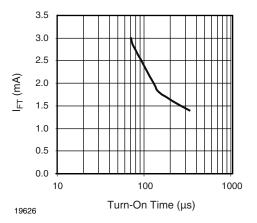


Fig. 8 - Trigger Current vs. Turn-On Time

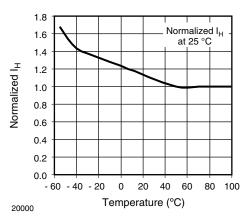
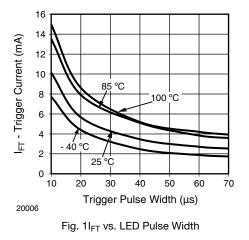
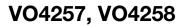


Fig. 9 - Normalized Holding Current vs. Temperature



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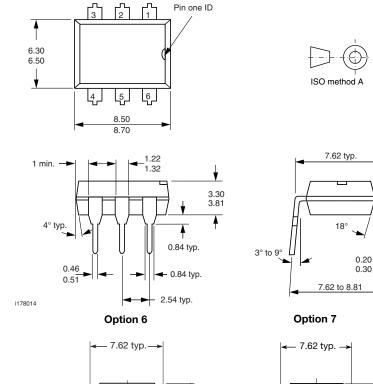
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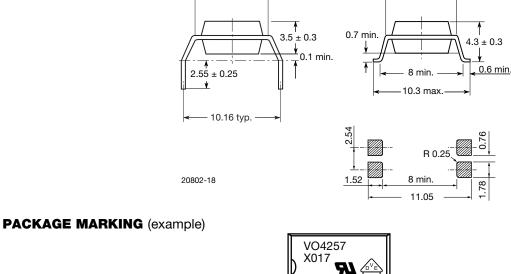
3.30 3.81

4

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PACKAGE DIMENSIONS in millimeters





Note

• VDE logo is only marked on option 1 parts. Tape and reel suffix (T) is not part of the package marking.

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